

Power CMOS Drivers With Voltage Tripler

Features:

- Power Driver With On-Board Voltage Booster
- Low I_{DD} : < 4 mA
- Small Package: 8-Pin PDIP
- Undervoltage Circuitry
- Fast Rise/Fall Time: <40 ns @1000 pF
- Below-Rail Input Protection

Applications:

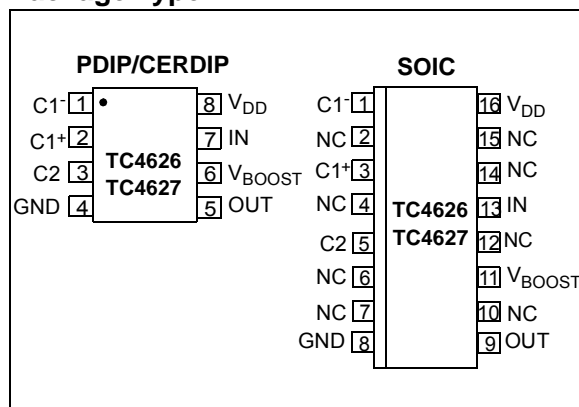
- Raises 5V to drive higher – V_{gs} (ON) MOSFETs
- Eliminates one system power supply

General Description:

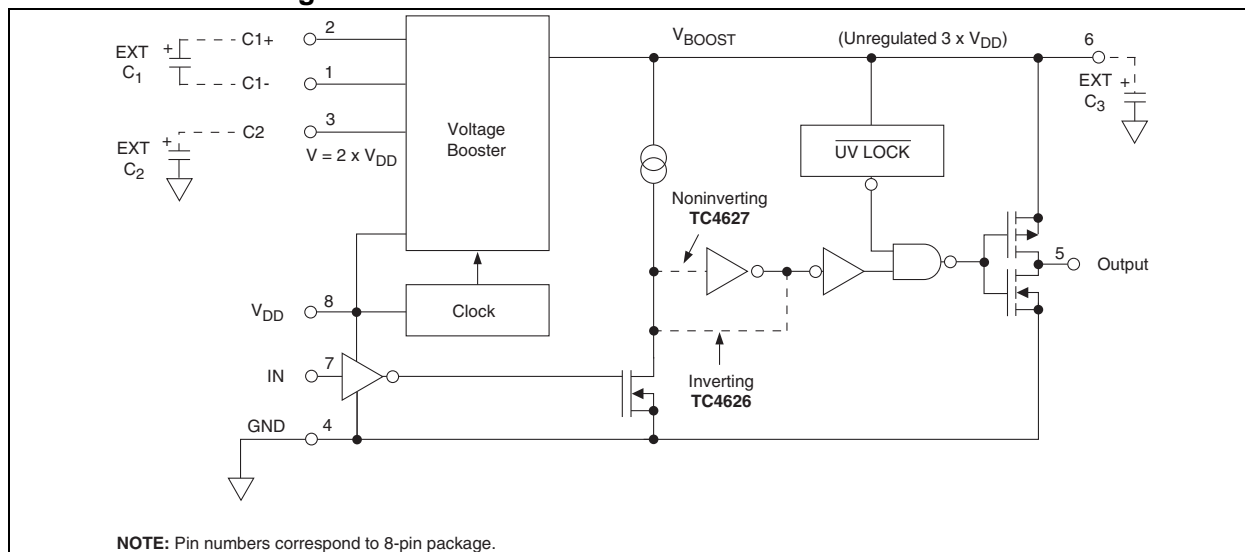
The TC4626/TC4627 are single CMOS high-speed drivers with an on-board voltage boost circuit. These parts work with an input supply voltage from 4 to 6 volts. The internal voltage booster will produce a V_{BOOST} potential up to 12 volts above V_{IN} . This V_{BOOST} is not regulated, so its voltage is dependent on the input V_{DD} voltage and output drive loading requirements. An internal undervoltage lockout circuit keeps the output in a low state when V_{BOOST} drops below 7.8 volts. Output is enabled when V_{BOOST} is above 11.3 volts.

Note: Check the Microchip web site for available package types and package information.

Package Type



Functional Block Diagram



TC4626/TC4627

1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings†

Supply Voltage	6.2V
Input Voltage, Any Terminal	$V_S + 0.3V$ to $GND - 0.3V$
Package Power Dissipation ($T_A \leq 70^\circ C$)	
PDIP	730 mW
CERDIP	800 mW
SOIC	760 mW
Derating Factor PDIP	5.6 mW/ $^\circ C$ Above $36^\circ C$
CERDIP	6.0 mW/ $^\circ C$
Operating Temperature Range (Ambient)	
C Version	$0^\circ C$ to $+70^\circ C$
E Version	$-40^\circ C$ to $+85^\circ C$
M Version	$-55^\circ C$ to $+125^\circ C$
Storage Temperature Range	$-65^\circ C$ to $+150^\circ C$

† **Notice:** Stresses above those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions above those indicated in the operation sections of the specifications is not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

TC4626/TC4627 ELECTRICAL SPECIFICATIONS

Electrical Characteristics: $T_A = +25^\circ C$, $V_{DD} = 5V$, $C_1 = C_2 = C_3 = 10\mu F$ unless otherwise noted.						
Parameter	Symbol	Min.	Typ.	Max.	Units	Test Conditions
Input						
Logic '1', High Input Voltage	V_{IH}	2.4	—	—	V	
Logic '0', Low Input Voltage	V_{IL}	—	—	0.8	V	
Input Current	I_{IN}	-1	—	+1	μA	$0V \leq V_{IN} \leq V_{DRIVE}$
Output						
High Output Voltage	V_{OH}	$V_{BOOST} - 0.025$	—	—	V	
Low Output Voltage	V_{OL}	—	—	0.025	V	
Output Resistance, High	R_O	—	10	15	Ω	$I_{OUT} = 10\text{ mA}$, $V_{DD} = 5V$
Output Resistance, Low	R_O	—	8	10	Ω	$I_{OUT} = 10\text{ mA}$, $V_{DD} = 5V$
Peak Output Current	I_{PK}	—	1.5	—	A	
Switching Time						
Rise Time	t_R	—	33	40	ns	Figure 3-1, Figure 3-2
Fall Time	t_F	—	27	35	ns	Figure 3-1, Figure 3-2
Delay Time	t_{D1}	—	35	45	ns	Figure 3-1, Figure 3-2
Delay Time	t_{D2}	—	45	55	ns	Figure 3-1, Figure 3-2
Maximum Switching Frequency	F_{MAX}	1.0	—	—	MHz	$V_{DD} = 5V$, $V_{BOOST} > 8.5V$, Figure 3-1
Voltage Booster						
Voltage Tripler Output Source Resistance	R_3	—	300	400	Ω	$I_L = 10\text{ mA}$, $V_{DD} = 5V$
Voltage Doubler Output Source Resistance	R_2	—	120	200	Ω	
Oscillator Frequency	F_{OSC}	12	—	28	kHz	
Oscillator Amplitude Measured at C1-	V_{OSC}	4.5	—	10	V	$R_{LOAD} = 10\text{ k}\Omega$
Undervoltage Threshold	$UV @ V_{BOOST}$	7.0	7.8	8.5	V	
Start-Up Voltage	$V_{START} @ V_{BOOST}$	10.5	11.3	12	V	

TC4626/TC4627 ELECTRICAL SPECIFICATIONS (CONTINUED)

Electrical Characteristics: $T_A = +25^\circ\text{C}$, $V_{DD} = 5\text{V}$, $C_1 = C_2 = C_3 = 10\mu\text{F}$ unless otherwise noted.						
Parameter	Symbol	Min.	Typ.	Max.	Units	Test Conditions
@ $V_{DD} = 5\text{V}$	V_{BOOST}	14.6	—	—	V	No Load
Power Supply						
Power Supply Current	I_{DD}	—	—	2.5	mA	$V_{\text{IN}} = \text{Low or High}$
Supply Voltage	V_{DD}	4.0	—	6.0	V	
Input						
Logic 1, High Input Voltage	V_{IH}	2.4	—	—	V	
Logic 0, Low Input Voltage	V_{IL}	—	—	0.8	V	
Input Current	I_{IN}	-10	—	1	μA	$0\text{V} \leq V_{\text{IN}} \leq V_{\text{BOOST}}$
Output						
High Output Voltage	V_{OH}	$V_{\text{DRIVE}} - 0.025$	—	—	V	
Low Output Voltage	V_{OL}	—	—	0.025	V	
Output Resistance, High	R_{O}	—	15 15	20 25	Ω	$I_{\text{OUT}} = 10\text{ mA}$, $V_{DD} = 5\text{V}$ C & E Version ($T_A = +70^\circ\text{C}$ or $+85^\circ\text{C}$) M Version ($T_A = +125^\circ\text{C}$)
Output Resistance, Low	R_{O}	—	10 10	13 15	Ω	$I_{\text{OUT}} = 10\text{ mA}$, $V_{DD} = 5\text{V}$ C & E Version ($T_A = +70^\circ\text{C}$ or $+85^\circ\text{C}$) M Version ($T_A = +125^\circ\text{C}$)
Peak Output Current	I_{PK}	—	1.5	—	A	
Switching Time						
Rise Time	t_{R}	—	—	55	ns	Figure 3-1, Figure 3-2
Fall Time	t_{F}	—	—	50	ns	Figure 3-1, Figure 3-2
Delay Time	t_{D1}	—	—	60	ns	Figure 3-1, Figure 3-2
Delay Time	t_{D2}	—	—	70	ns	Figure 3-1, Figure 3-2
Maximum Switching Frequency	F_{MAX}	750	—	—	kHz	$V_{DD} = 5\text{V}$, $V_{\text{BOOST}} > 8.5\text{V}$, Figure 3-1
Voltage Booster						
Voltage Boost Output Source Resistance	R_3	—	400	500	Ω	$I_{\text{L}} = 10\text{ mA}$, $V_{DD} = 5\text{V}$
Voltage Doubler Output Source Resistance	R_2	—	170	300	Ω	
Oscillator Frequency	F_{OSC}	5	—	50	kHz	
Oscillator Amplitude Measured at C1-	V_{OSC}	4.5	—	10	V	$R_{\text{LOAD}} = 10\text{ k}\Omega$
Undervoltage Threshold	$\text{UV @ } V_{\text{BOOST}}$	7.0	7.8	8.5	V	
Start-Up Voltage	$V_{\text{START @ } V_{\text{BOOST}}}$	10.5	11.3	12	V	
@ $V_{DD} = 5\text{V}$	V_{BOOST}	14.6	—	—	V	No Load
Power Supply						
Power Supply Current	I_{DD}	—	—	4	mA	$V_{\text{IN}} = \text{Low or High}$
Supply Voltage	V_{DD}	4.0	—	6.0	V	

TC4626/TC4627

2.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in [Table 2-1](#).

TABLE 2-1: PIN FUNCTION TABLE

Pin No. (8-Pin PDIP, CERDIP)	Pin No. (16-Pin SOIC Wide)	Symbol	Description
1	1	C1-	See Section 3.1 “Booster Function” for description
2	3	C1+	See Section 3.1 “Booster Function” for description
3	5	C2	See Section 3.1 “Booster Function” for description
4	8	GND	Ground.
5	9	OUT	Output
6	11	V _{BOOST}	See Section 3.1 “Booster Function” for description
7	13	IN	Control Input
8	16	V _{DD}	Supply Input
—	2, 4, 6, 7, 10, 12, 14, 15	NC	Not connected.

3.0 APPLICATIONS INFORMATION

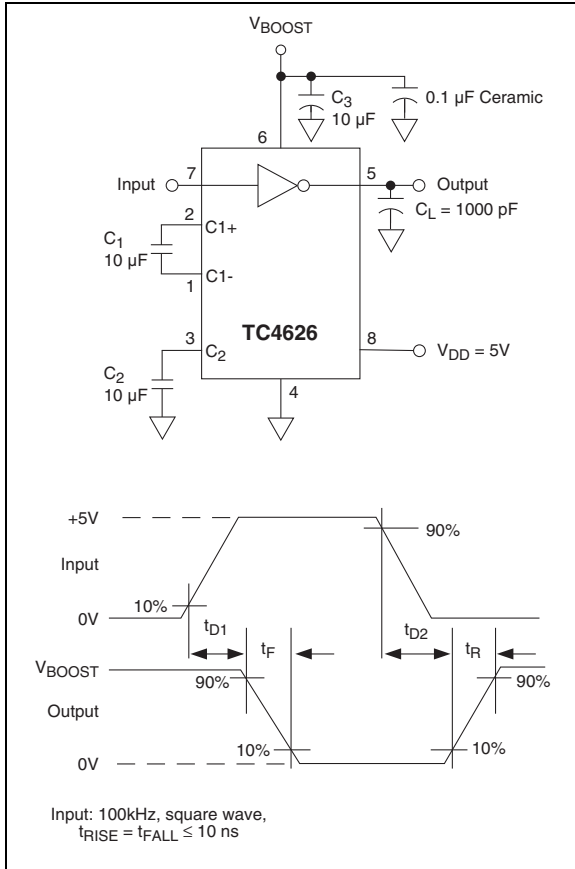


FIGURE 3-1: Inverting Driver Switching Time.

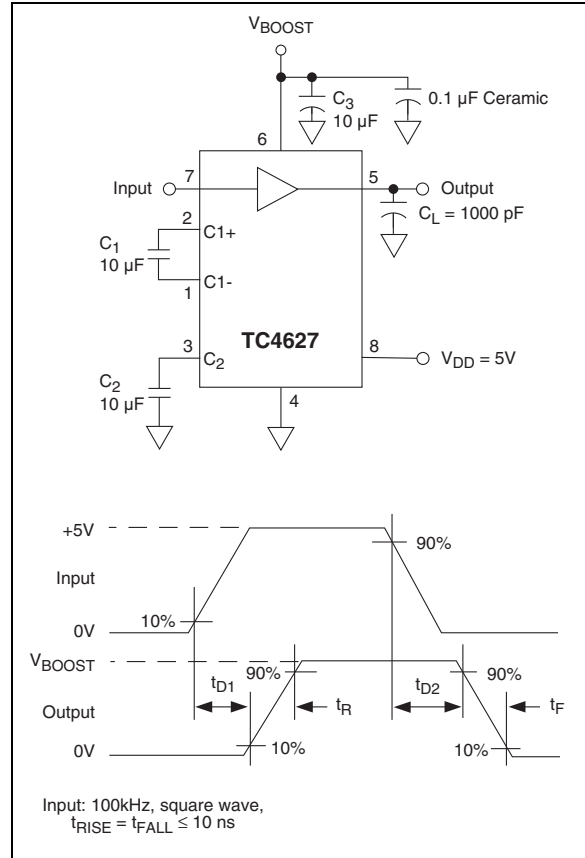


FIGURE 3-2: Noninverting Driver Switching Time.

TC4626/TC4627

3.1 BOOSTER FUNCTION

The voltage booster is an unregulated voltage tripler circuit. The tripler consists of three sets of internal switches and three external capacitors. S1a and S1b charge capacitor C1 to V_{DD} potential. S2a and S2b add C1 potential to V_{DD} input to charge C2 to $2 \times V_{DD}$. S3a and S3b add C1 potential to C2 to charge C3 to $3 \times V_{DD}$. The position of the switches is controlled by the internal four-phase clock.

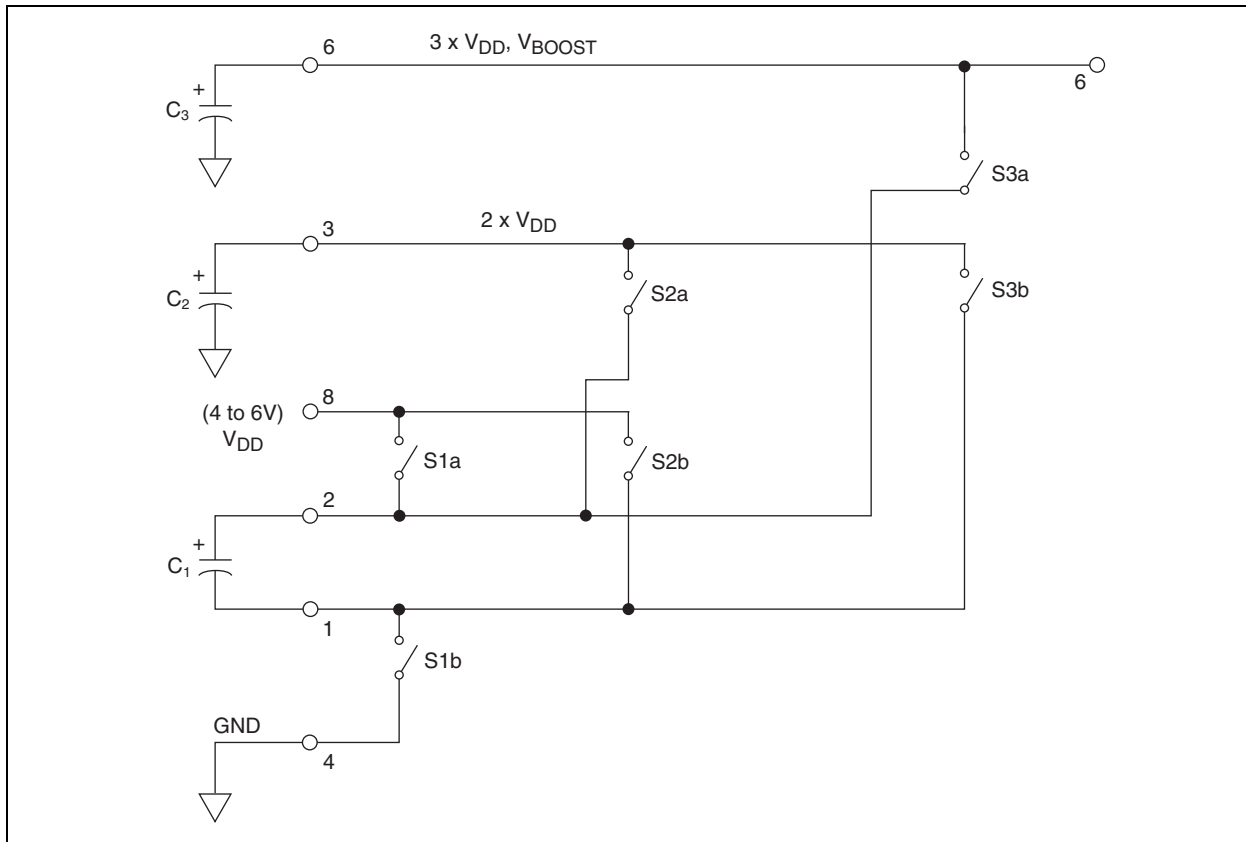


FIGURE 3-3: Voltage Booster.

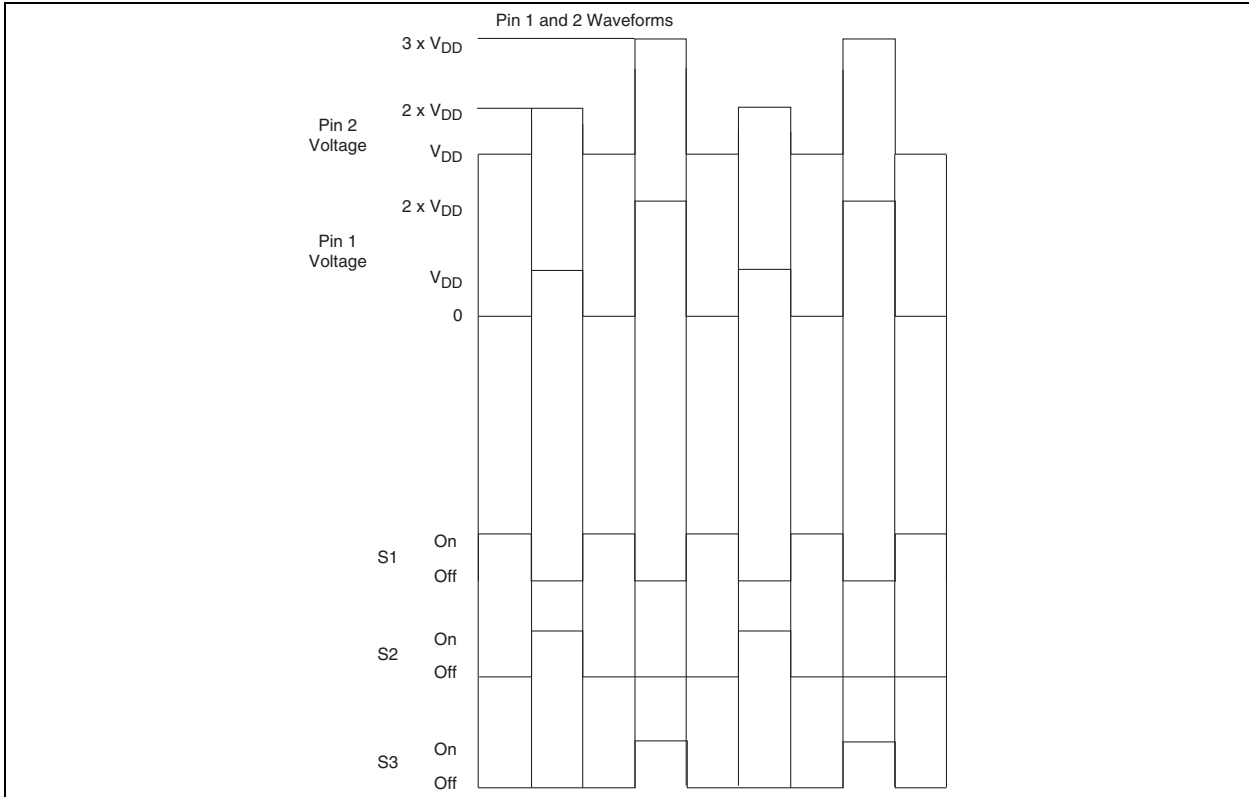
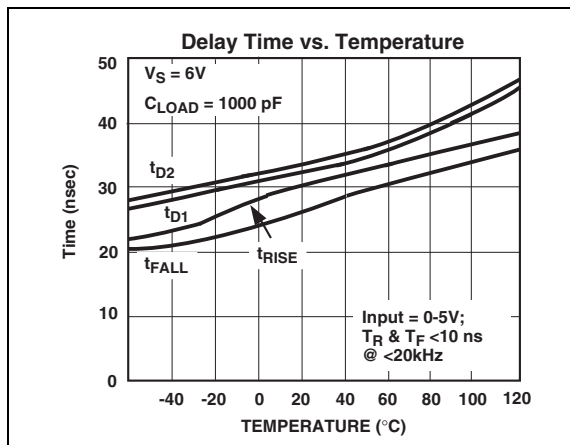
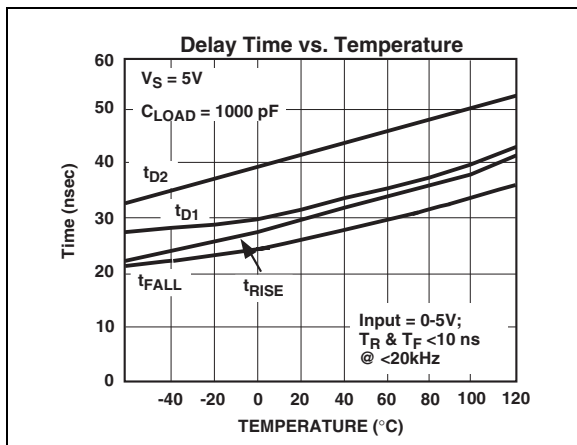
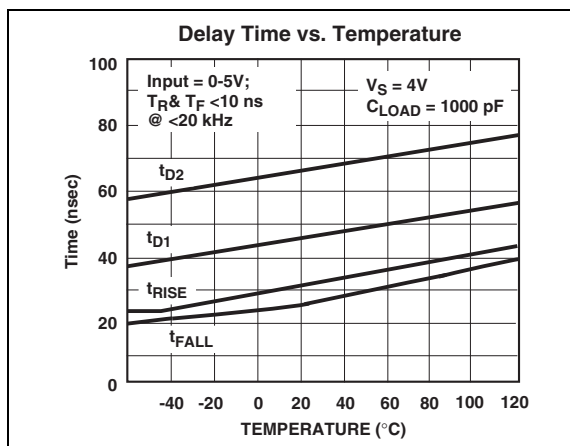
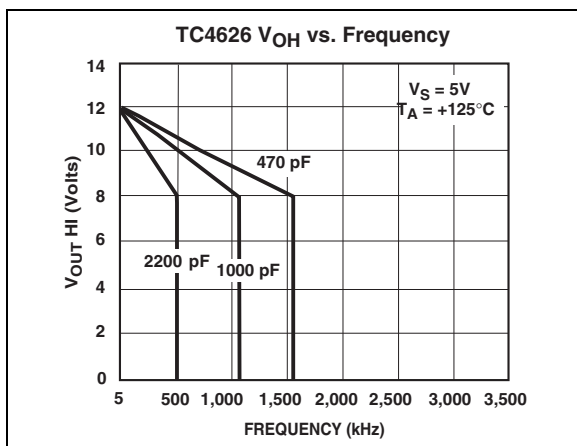
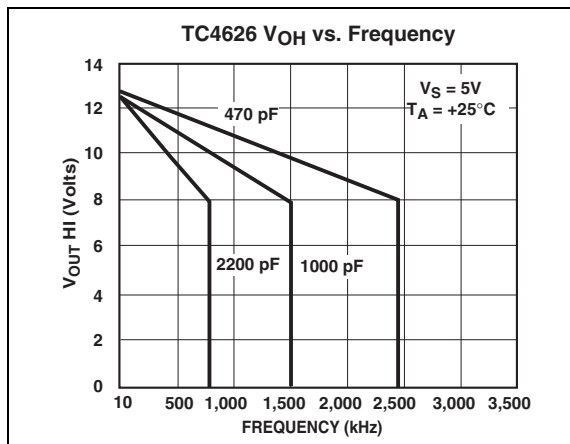
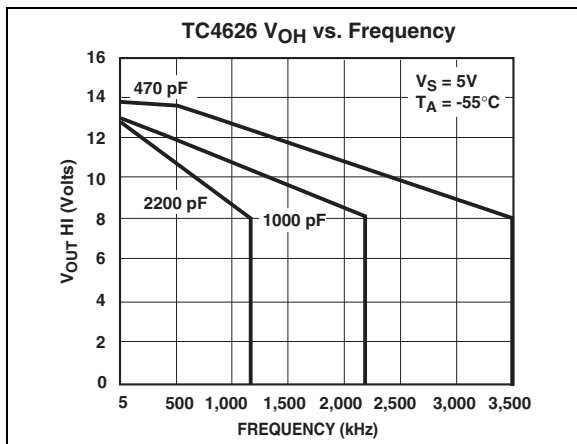


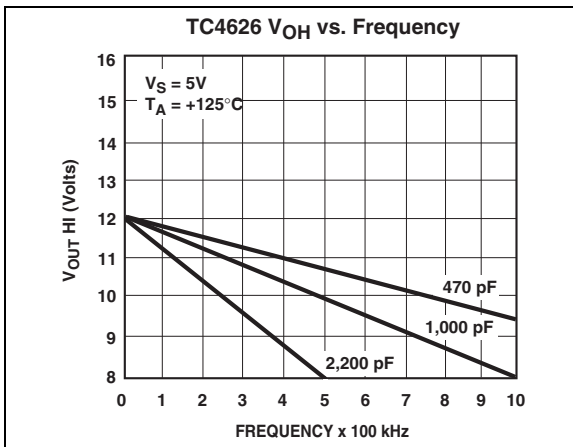
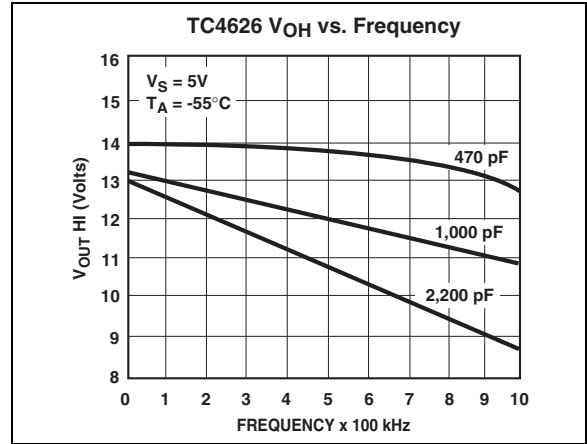
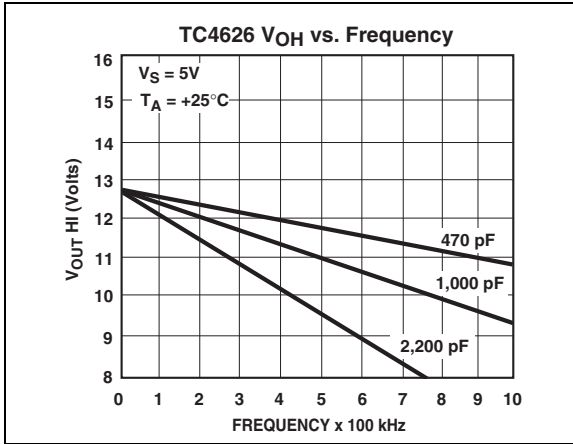
FIGURE 3-4: Position of Switches.

TC4626/TC4627

4.0 TYPICAL CHARACTERISTICS

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.



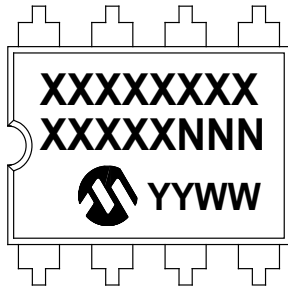


TC4626/TC4627

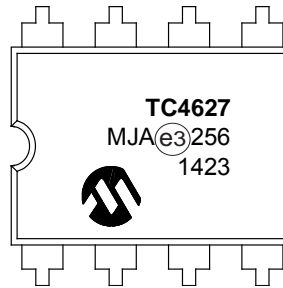
5.0 PACKAGING INFORMATION

5.1 Package Marking Information

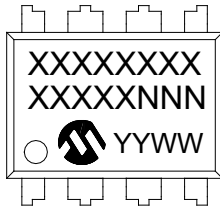
8-Lead CERDIP (.300") (TC4627 Only)



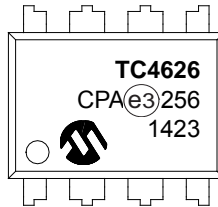
Example



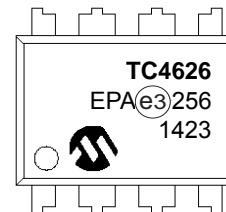
8-Lead PDIP (300 mil)



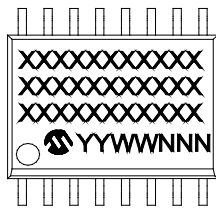
Example



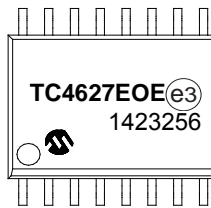
OR



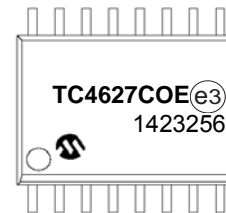
16-Lead SOIC (7.50 mm)



Example



OR

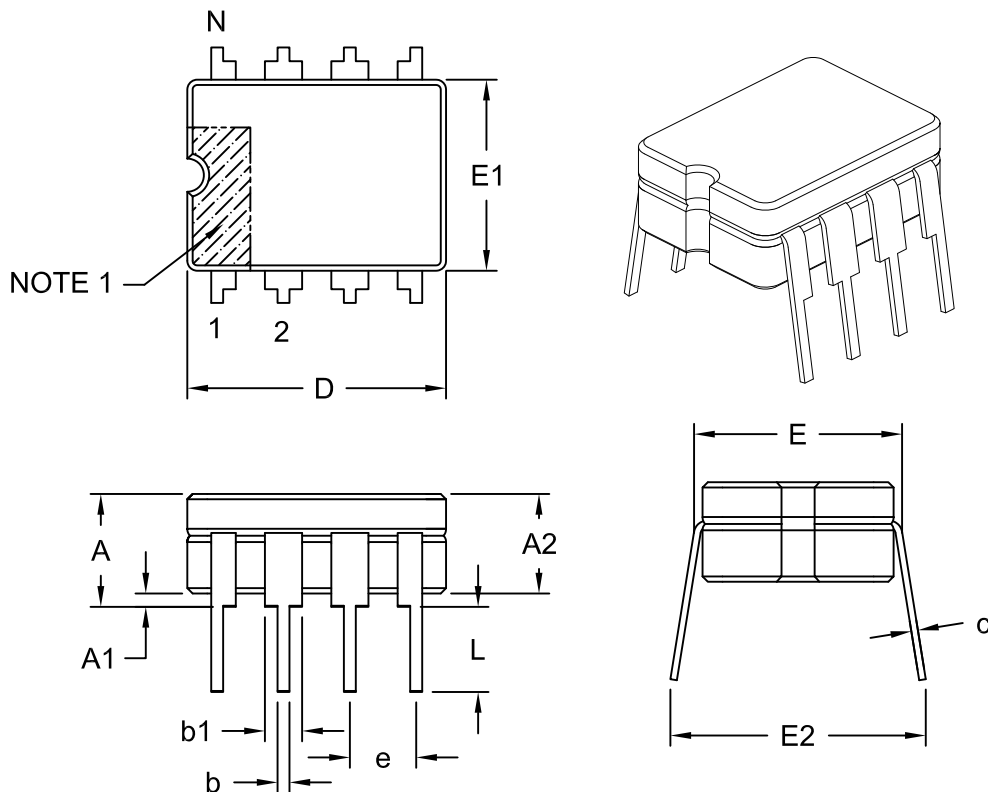


Legend:	XX...X	Customer-specific information
	Y	Year code (last digit of calendar year)
	YY	Year code (last 2 digits of calendar year)
	WW	Week code (week of January 1 is week '01')
	NNN	Alphanumeric traceability code
	(e3)	Pb-free JEDEC® designator for Matte Tin (Sn)
	*	This package is Pb-free. The Pb-free JEDEC designator (e3) can be found on the outer packaging for this package.

Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information.

8-Lead Ceramic Dual In-Line (JA) ~ .300" Body [CERDIP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



		Units	INCHES		
Dimension Limits			MIN	NOM	MAX
Number of Pins	N		8		
Pitch	e		.100 BSC		
Top to Seating Plane	A	-	-	-	.200
Base to Seating Plane §	A1	.015	-	-	-
Ceramic Package Height	A2	.140	-	-	.175
Shoulder to Shoulder Width	E	.290	-	-	.320
Ceramic Pkg. Width	E1	.230	.248	-	.300
Overall Length	D	.370	.380	-	.400
Tip to Seating Plane	L	.125	-	-	.200
Lead Thickness	c	.008	-	-	.015
Upper Lead Width	b1	.045	-	-	.065
Lower Lead Width	b	.015	-	-	.023
Overall Row Spacing	E2	.314	-	-	.410

Notes:

- Pin 1 visual index feature may vary, but must be located within the hatched area.
- § Significant Characteristic
- Dimensioning and tolerancing per ASME Y14.5M

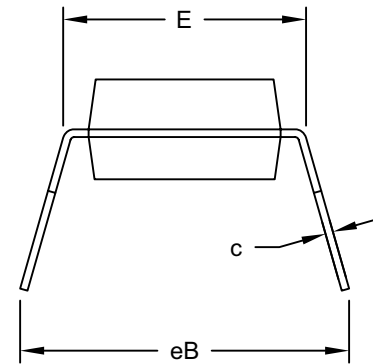
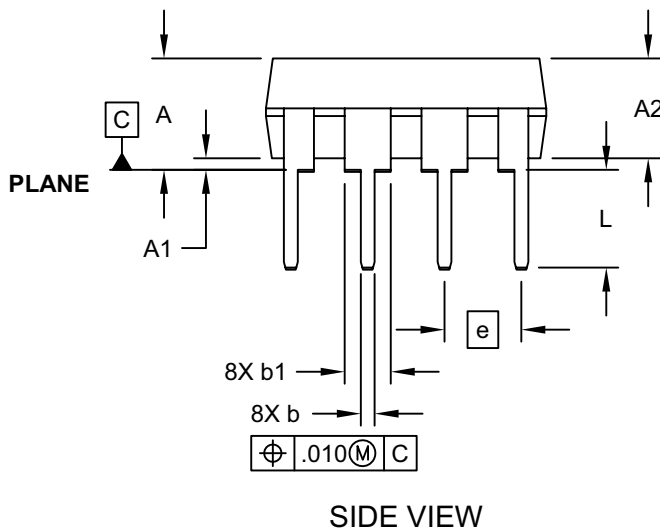
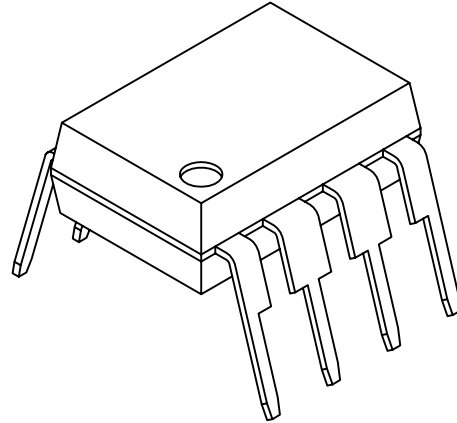
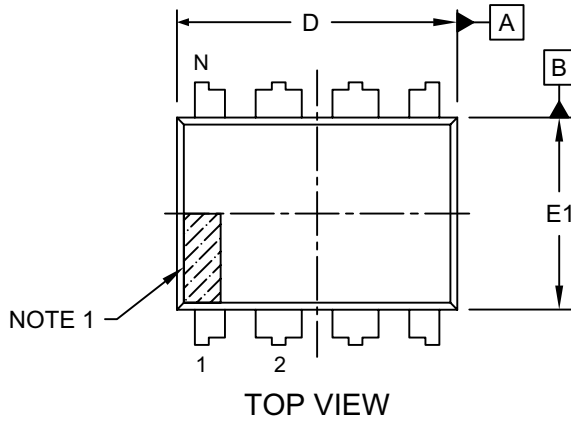
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-001C

TC4626/TC4627

8-Lead Plastic Dual In-Line (PA) - 300 mil Body [PDIP]

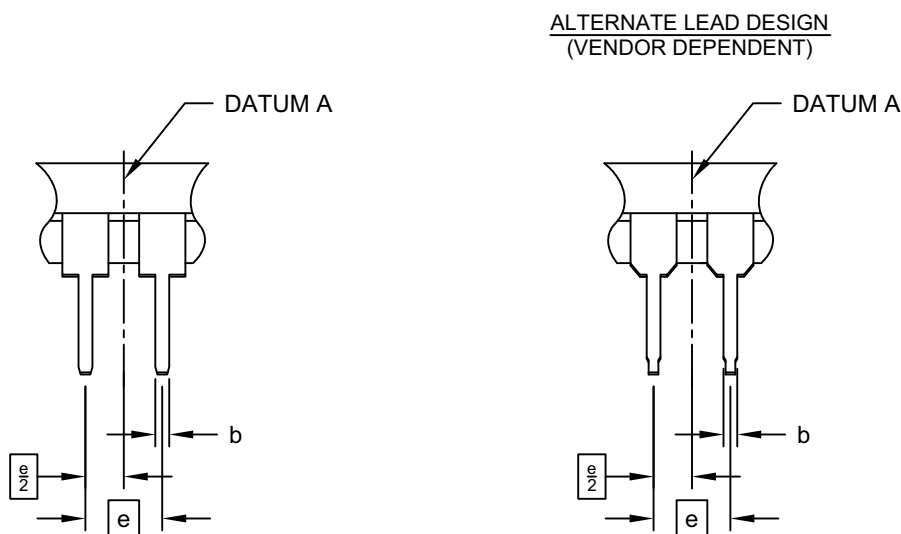
Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



Microchip Technology Drawing No. C04-018D Sheet 1 of 2

8-Lead Plastic Dual In-Line (PA) - 300 mil Body [PDIP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



Dimension Limits	Units	INCHES		
		MIN	NOM	MAX
Number of Pins	N	8		
Pitch	e	.100 BSC		
Top to Seating Plane	A	-	-	.210
Molded Package Thickness	A2	.115	.130	.195
Base to Seating Plane	A1	.015	-	-
Shoulder to Shoulder Width	E	.290	.310	.325
Molded Package Width	E1	.240	.250	.280
Overall Length	D	.348	.365	.400
Tip to Seating Plane	L	.115	.130	.150
Lead Thickness	c	.008	.010	.015
Upper Lead Width	b1	.040	.060	.070
Lower Lead Width	b	.014	.018	.022
Overall Row Spacing	§ eB	-	-	.430

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.
2. § Significant Characteristic
3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" per side.
4. Dimensioning and tolerancing per ASME Y14.5M

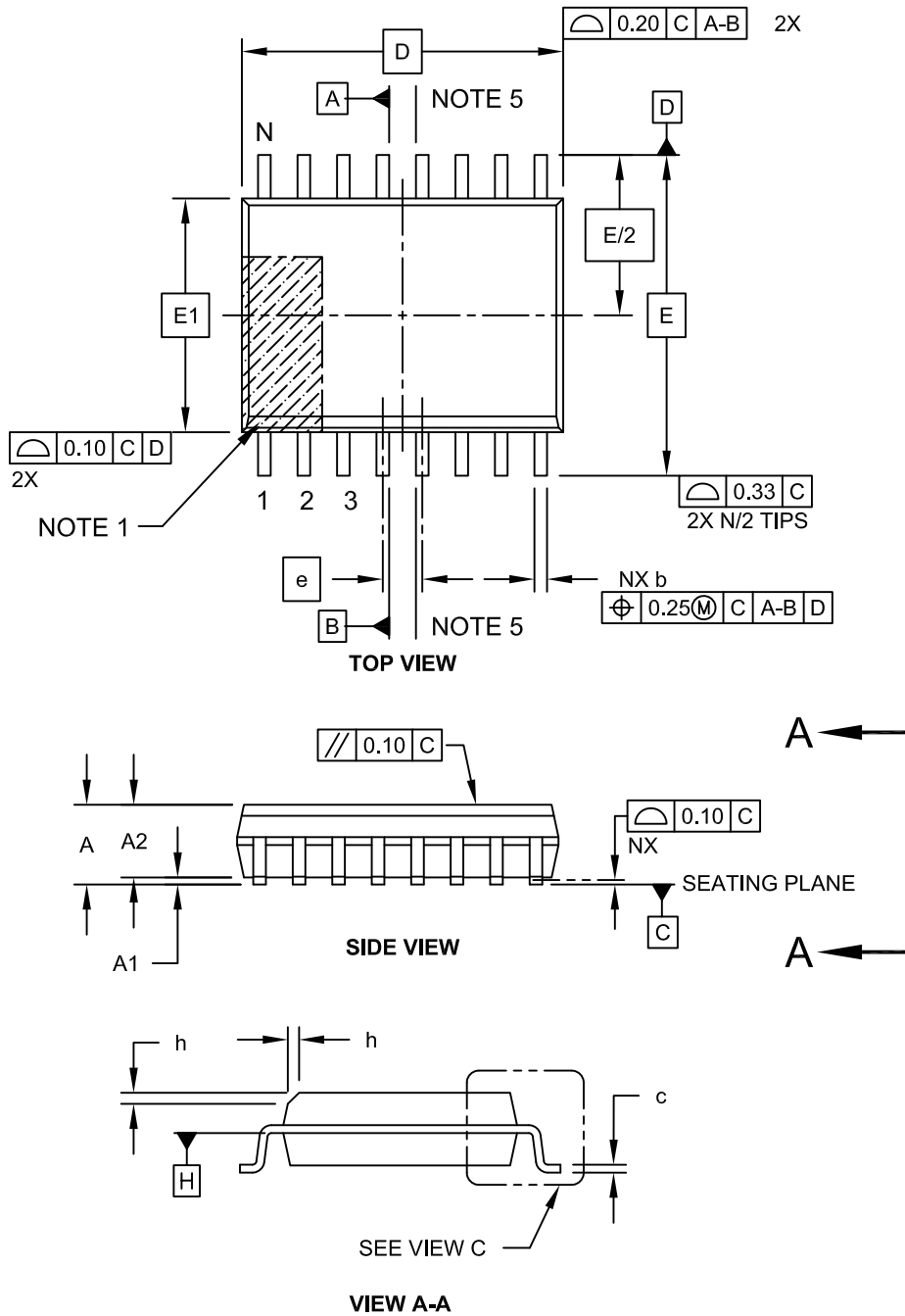
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-018D Sheet 2 of 2

TC4626/TC4627

16-Lead Plastic Small Outline (OE) - Wide, 7.50 mm Body [SOIC]

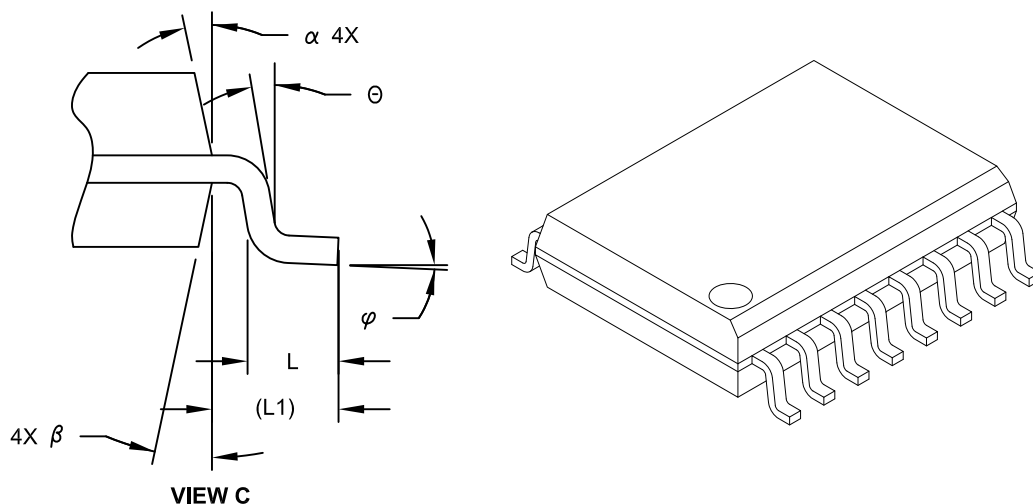
Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



Microchip Technology Drawing C04-102C Sheet 1 of 2

16-Lead Plastic Small Outline (OE) - Wide, 7.50 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



Dimension Limits	Units	MILLIMETERS		
		MIN	NOM	MAX
Number of Pins	N	16		
Pitch	e	1.27 BSC		
Overall Height	A	-	-	2.65
Molded Package Thickness	A2	2.05	-	-
Standoff §	A1	0.10	-	0.30
Overall Width	E	10.30 BSC		
Molded Package Width	E1	7.50 BSC		
Overall Length	D	10.30 BSC		
Chamfer (Optional)	h	0.25	-	0.75
Foot Length	L	0.40	-	1.27
Footprint	L1	1.40 REF		
Lead Angle	θ	0°	-	-
Foot Angle	φ	0°	-	8°
Lead Thickness	c	0.20	-	0.33
Lead Width	b	0.31	-	0.51
Mold Draft Angle Top	α	5°	-	15°
Mold Draft Angle Bottom	β	5°	-	15°

Notes:

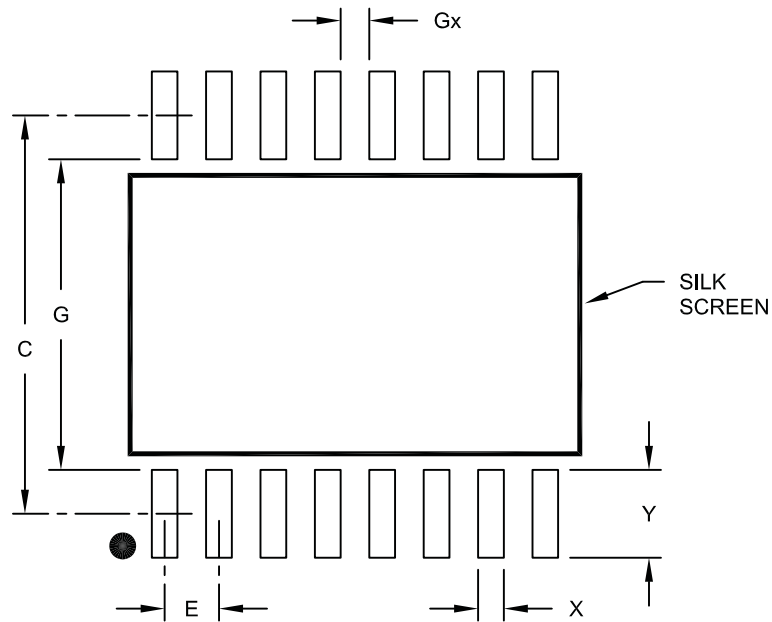
- Pin 1 visual index feature may vary, but must be located within the hatched area.
- § Significant Characteristic
- Dimension D does not include mold flash, protrusions or gate burrs, which shall not exceed 0.15 mm per end. Dimension E1 does not include interlead flash or protrusion, which shall not exceed 0.25 mm per side.
- Dimensioning and tolerancing per ASME Y14.5M
 BSC: Basic Dimension. Theoretically exact value shown without tolerances.
 REF: Reference Dimension, usually without tolerance, for information purposes only.
- Datums A & B to be determined at Datum H.

Microchip Technology Drawing No. C04-102C Sheet 2 of 2

TC4626/TC4627

16-Lead Plastic Small Outline (OE) – Wide, 7.50 mm Body [SOIC] Land Pattern

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



RECOMMENDED LAND PATTERN

Dimension Limits	Units	MILLIMETERS		
		MIN	NOM	MAX
Contact Pitch	E	1.27 BSC		
Contact Pad Spacing	C		9.30	
Contact Pad Width	X			0.60
Contact Pad Length	Y			2.05
Distance Between Pads	Gx	0.67		
Distance Between Pads	G	7.25		

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2102A

APPENDIX A: REVISION HISTORY

Revision D (July 2014)

The following is the list of modifications:

- Restructured [Table 2-1](#) for readability purposes.
- Updated package specification drawings in [Section 5.0, Packaging Information](#) to match all views available.
- Added new [Product Identification System](#).

Revision C (December 2012)

Added a note to each package outline drawing.

TC4626/TC4627

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

<u>PART NO.</u>	-	<u>X</u>	<u>/XX</u>
Device		Temperature Range	Package
Device:	TC4626:	Single CMOS High-Speed Driver, Inverting	
	TC4627:	Single CMOS High-Speed Driver, Non-Inverting	
Temperature Range:	C =	0°C to +70°C	
	E =	-40°C to +85°C	
Package:	JA =	8-Lead Ceramic Dual In-Line, 300" Body (CERDIP) (TC4627 only)	
	OE =	16-Lead Plastic Small Outline, Wide, 7.50 mm Body (SOIC)	
	PA =	8-Lead Plastic Dual In-Line, 300 mil Body (PDIP)	

Examples:

a) TC4626CPA: High-Speed Inverting Single CMOS Driver, 0°C to +70°C.

b) TC4626EPA: High-Speed Inverting Single CMOS Driver, -40°C to +85°C.

Note the following details of the code protection feature on Microchip devices:

- Microchip products meet the specification contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is one of the most secure families of its kind on the market today, when used in the intended manner and under normal conditions.
- There are dishonest and possibly illegal methods used to breach the code protection feature. All of these methods, to our knowledge, require using the Microchip products in a manner outside the operating specifications contained in Microchip's Data Sheets. Most likely, the person doing so is engaged in theft of intellectual property.
- Microchip is willing to work with the customer who is concerned about the integrity of their code.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of their code. Code protection does not mean that we are guaranteeing the product as “unbreakable.”

Code protection is constantly evolving. We at Microchip are committed to continuously improving the code protection features of our products. Attempts to break Microchip's code protection feature may be a violation of the Digital Millennium Copyright Act. If such acts allow unauthorized access to your software or other copyrighted work, you may have a right to sue for relief under that Act.

Information contained in this publication regarding device applications and the like is provided only for your convenience and may be superseded by updates. It is your responsibility to ensure that your application meets with your specifications. MICROCHIP MAKES NO REPRESENTATIONS OR WARRANTIES OF ANY KIND WHETHER EXPRESS OR IMPLIED, WRITTEN OR ORAL, STATUTORY OR OTHERWISE, RELATED TO THE INFORMATION, INCLUDING BUT NOT LIMITED TO ITS CONDITION, QUALITY, PERFORMANCE, MERCHANTABILITY OR FITNESS FOR PURPOSE. Microchip disclaims all liability arising from this information and its use. Use of Microchip devices in life support and/or safety applications is entirely at the buyer's risk, and the buyer agrees to defend, indemnify and hold harmless Microchip from any and all damages, claims, suits, or expenses resulting from such use. No licenses are conveyed, implicitly or otherwise, under any Microchip intellectual property rights.

Trademarks

The Microchip name and logo, the Microchip logo, dsPIC, FlashFlex, flexPWR, JukeBlox, KEELOQ, KEELOQ logo, Kleer, LANCheck, MediaLB, MOST, MOST logo, MPLAB, OptoLyzer, PIC, PICSTART, PIC³² logo, RightTouch, SpyNIC, SST, SST Logo, SuperFlash and UNI/O are registered trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

The Embedded Control Solutions Company and mTouch are registered trademarks of Microchip Technology Incorporated in the U.S.A.

Analog-for-the-Digital Age, BodyCom, chipKIT, chipKIT logo, CodeGuard, dsPICDEM, dsPICDEM.net, ECAN, In-Circuit Serial Programming, ICSP, Inter-Chip Connectivity, KleerNet, KleerNet logo, MiWi, MPASM, MPF, MPLAB Certified logo, MPLIB, MPLINK, MultiTRAK, NetDetach, Omniscient Code Generation, PICDEM, PICDEM.net, PICkit, PICtail, RightTouch logo, REAL ICE, SQI, Serial Quad I/O, Total Endurance, TSHARC, USBCheck, VariSense, ViewSpan, WiperLock, Wireless DNA, and ZENA are trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

SQTP is a service mark of Microchip Technology Incorporated in the U.S.A.

Silicon Storage Technology is a registered trademark of Microchip Technology Inc. in other countries.

GestIC is a registered trademarks of Microchip Technology Germany II GmbH & Co. KG, a subsidiary of Microchip Technology Inc., in other countries.

All other trademarks mentioned herein are property of their respective companies.

© 2001-2014, Microchip Technology Incorporated, Printed in the U.S.A., All Rights Reserved.

ISBN: 978-1-63276-380-8

QUALITY MANAGEMENT SYSTEM
CERTIFIED BY DNV
== ISO/TS 16949 ==

Microchip received ISO/TS-16949:2009 certification for its worldwide headquarters, design and wafer fabrication facilities in Chandler and Tempe, Arizona; Gresham, Oregon and design centers in California and India. The Company's quality system processes and procedures are for its PIC[®] MCUs and dsPIC[®] DSCs, KEELOQ[®] code hopping devices, Serial EEPROMs, microperipherals, nonvolatile memory and analog products. In addition, Microchip's quality system for the design and manufacture of development systems is ISO 9001:2000 certified.



MICROCHIP

Worldwide Sales and Service

AMERICAS

Corporate Office
2355 West Chandler Blvd.
Chandler, AZ 85224-6199
Tel: 480-792-7200
Fax: 480-792-7277
Technical Support:
<http://www.microchip.com/support>
Web Address:
www.microchip.com

Atlanta
Duluth, GA
Tel: 678-957-9614
Fax: 678-957-1455

Austin, TX
Tel: 512-257-3370

Boston
Westborough, MA
Tel: 774-760-0087
Fax: 774-760-0088

Chicago
Itasca, IL
Tel: 630-285-0071
Fax: 630-285-0075

Cleveland
Independence, OH
Tel: 216-447-0464
Fax: 216-447-0643

Dallas
Addison, TX
Tel: 972-818-7423
Fax: 972-818-2924

Detroit
Novi, MI
Tel: 248-848-4000

Houston, TX
Tel: 281-894-5983

Indianapolis
Noblesville, IN
Tel: 317-773-8323
Fax: 317-773-5453

Los Angeles
Mission Viejo, CA
Tel: 949-462-9523
Fax: 949-462-9608

New York, NY
Tel: 631-435-6000

San Jose, CA
Tel: 408-735-9110

Canada - Toronto
Tel: 905-673-0699
Fax: 905-673-6509

ASIA/PACIFIC

Asia Pacific Office
Suites 3707-14, 37th Floor
Tower 6, The Gateway
Harbour City, Kowloon
Hong Kong
Tel: 852-2943-5100
Fax: 852-2401-3431

Australia - Sydney
Tel: 61-2-9868-6733
Fax: 61-2-9868-6755

China - Beijing
Tel: 86-10-8569-7000
Fax: 86-10-8528-2104

China - Chengdu
Tel: 86-28-8665-5511
Fax: 86-28-8665-7889

China - Chongqing
Tel: 86-23-8980-9588
Fax: 86-23-8980-9500

China - Hangzhou
Tel: 86-571-8792-8115
Fax: 86-571-8792-8116

China - Hong Kong SAR
Tel: 852-2943-5100
Fax: 852-2401-3431

China - Nanjing
Tel: 86-25-8473-2460
Fax: 86-25-8473-2470

China - Qingdao
Tel: 86-532-8502-7355
Fax: 86-532-8502-7205

China - Shanghai
Tel: 86-21-5407-5533
Fax: 86-21-5407-5066

China - Shenyang
Tel: 86-24-2334-2829
Fax: 86-24-2334-2393

China - Shenzhen
Tel: 86-755-8864-2200
Fax: 86-755-8203-1760

China - Wuhan
Tel: 86-27-5980-5300
Fax: 86-27-5980-5118

China - Xian
Tel: 86-29-8833-7252
Fax: 86-29-8833-7256

China - Xiamen
Tel: 86-592-2388138
Fax: 86-592-2388130

China - Zhuhai
Tel: 86-756-3210040
Fax: 86-756-3210049

ASIA/PACIFIC

India - Bangalore
Tel: 91-80-3090-4444
Fax: 91-80-3090-4123

India - New Delhi
Tel: 91-11-4160-8631
Fax: 91-11-4160-8632

India - Pune
Tel: 91-20-3019-1500

Japan - Osaka
Tel: 81-6-6152-7160
Fax: 81-6-6152-9310

Japan - Tokyo
Tel: 81-3-6880-3770
Fax: 81-3-6880-3771

Korea - Daegu
Tel: 82-53-744-4301
Fax: 82-53-744-4302

Korea - Seoul
Tel: 82-2-554-7200
Fax: 82-2-558-5932 or
82-2-558-5934

Malaysia - Kuala Lumpur
Tel: 60-3-6201-9857
Fax: 60-3-6201-9859

Malaysia - Penang
Tel: 60-4-227-8870
Fax: 60-4-227-4068

Philippines - Manila
Tel: 63-2-634-9065
Fax: 63-2-634-9069

Singapore
Tel: 65-6334-8870
Fax: 65-6334-8850

Taiwan - Hsin Chu
Tel: 886-3-5778-366
Fax: 886-3-5770-955

Taiwan - Kaohsiung
Tel: 886-7-213-7830

Taiwan - Taipei
Tel: 886-2-2508-8600
Fax: 886-2-2508-0102

Thailand - Bangkok
Tel: 66-2-694-1351
Fax: 66-2-694-1350

EUROPE

Austria - Wels
Tel: 43-7242-2244-39
Fax: 43-7242-2244-393

Denmark - Copenhagen
Tel: 45-4450-2828
Fax: 45-4485-2829

France - Paris
Tel: 33-1-69-53-63-20
Fax: 33-1-69-30-90-79

Germany - Dusseldorf
Tel: 49-2129-3766400

Germany - Munich
Tel: 49-89-627-144-0
Fax: 49-89-627-144-44

Germany - Pforzheim
Tel: 49-7231-424750

Italy - Milan
Tel: 39-0331-742611
Fax: 39-0331-466781

Italy - Venice
Tel: 39-049-7625286

Netherlands - Drunen
Tel: 31-416-690399
Fax: 31-416-690340

Poland - Warsaw
Tel: 48-22-3325737

Spain - Madrid
Tel: 34-91-708-08-90
Fax: 34-91-708-08-91

Sweden - Stockholm
Tel: 46-8-5090-4654

UK - Wokingham
Tel: 44-118-921-5800
Fax: 44-118-921-5820

03/25/14